

#### N-CHANNEL ENHANCEMENT MODE MOSFET

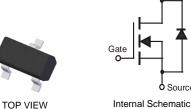
### **Features**

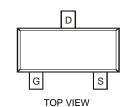
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminals Connections: See Diagram Below
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)







**Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characte	eristic		Symbol	Value	Units
Drain-Source Voltage			$V_{DSS}$	20	V
Gate-Source Voltage		V <sub>GSS</sub>	±8	V	
Continuous Drain Current (Note 3)	Steady State	T <sub>A</sub> = 25°C T <sub>A</sub> = 70°C	I <sub>D</sub>	4.2 3.4	А
Pulsed Drain Current (Note 4)			I <sub>DM</sub>	27	Α

Drain

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 3)	$P_{D}$	0.8 0.5	W	
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = 2	R <sub>0JA</sub>	156	°C/W	
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C	

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- 3. Device mounted on FR-4 PCB, with minimum recommended pad layout.
- 4. Repetitive rating, pulse width limited by junction temperature.

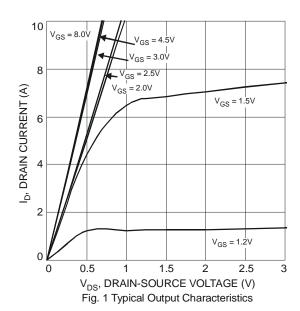


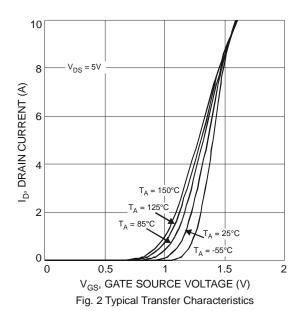
## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	-	-	V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current TJ = 25°C	I <sub>DSS</sub>	-	-	1.0	μΑ	$V_{DS} = 20V$ , $V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 8V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.4	-	1.0	V	$V_{DS} = V_{GS}$ , $I_D = 50\mu A$	
Static Drain-Source On-Resistance	P (0.1)	_	-	90 120	$m\Omega$	$V_{GS} = 4.5V, I_D = 3.6A$	
Static Dialit-Source Off-Resistance	R <sub>DS (ON)</sub>	-				$V_{GS} = 2.5V, I_D = 3.1A$	
Forward Transfer Admittance	Y <sub>fs</sub>	-	13	-	S	$V_{DS} = 5V, I_{D} = 3.6A$	
Diode Forward Voltage	$V_{SD}$	-	0.75	1.0	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	C <sub>iss</sub>	-	594.3	-	pF	101/1/	
Output Capacitance	Coss	-	64.5	-	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	$C_{rss}$	-	57.7	-	рF	1 – 1.001112	
Gate Resistance	$R_g$	-	1.5	ı	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg	-	7.0	-	nC ,	\\\\ 4.5\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	
Gate-Source Charge	Q <sub>gs</sub>	-	0.9	-	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$	
Gate-Drain Charge	$Q_{gd}$	-	1.4	-	nC	$I_D = 3.6A$	
Turn-On Delay Time	t <sub>D(on)</sub>	-	7.4	-	ns		
Turn-On Rise Time	t <sub>r</sub>	-	9.8	-	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$	
Turn-Off Delay Time	t <sub>D(off)</sub>	-	28.1	-	ns	$R_L = 2.78\Omega$ , $R_G = 1.0\Omega$	
Turn-Off Fall Time	t <sub>f</sub>	-	6.7	-	ns		

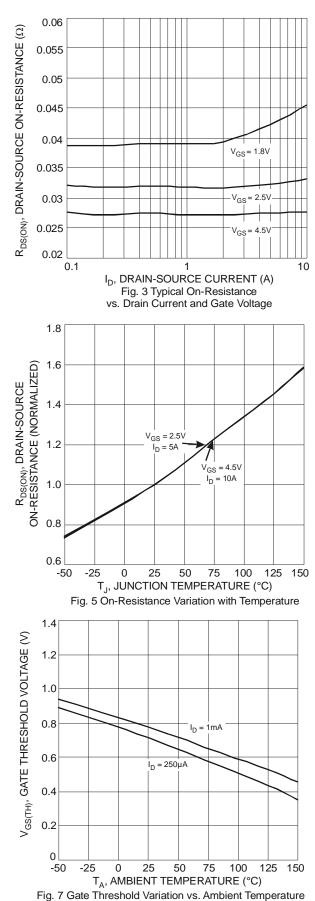
Notes:

- 5. Short duration pulse test used to minimize self-heating effect.
- 6. Guaranteed by design. Not subject to production testing.









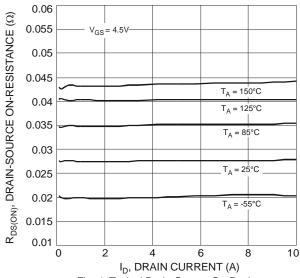


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature

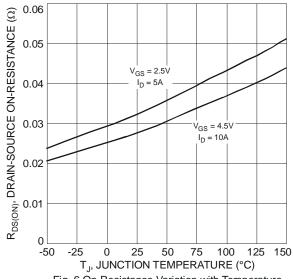
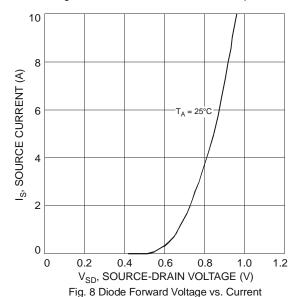


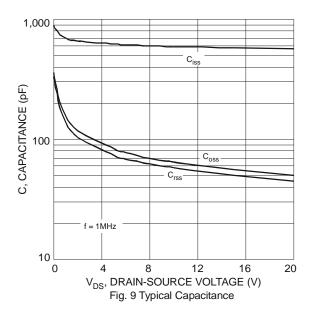
Fig. 6 On-Resistance Variation with Temperature

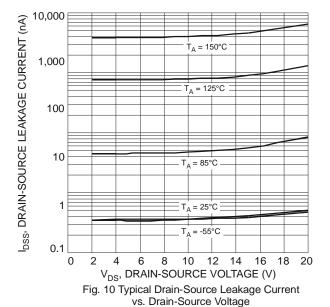


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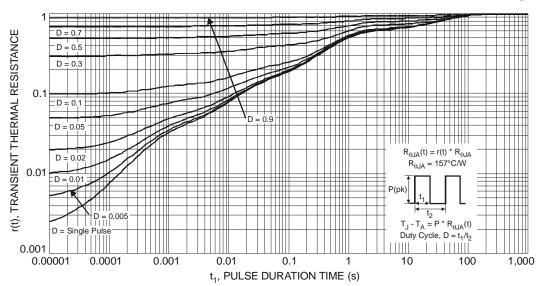


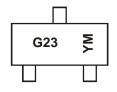
Fig. 11 Transient Thermal Response

## Ordering Information (Note 7)

Part Number	Case	Packaging
DMG2302U-7	SOT-23	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



G23 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: W = 2009)

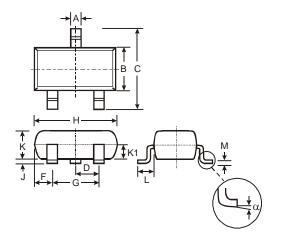
M = Month (ex: 9 = September)

Date Code Key

Year	2009	9	2010		2011	20	12	2013		2014	2	2015
Code	W		Х		Υ	1	7	Α		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

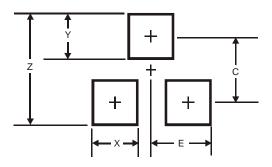


# **Package Outline Dimensions**



SOT-23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	-	0.400		
L	0.45	0.61	0.55		
M	0.085	0.18	0.11		
α	0°	8°	-		
All	All Dimensions in mm				

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35



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